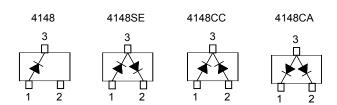
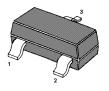


Silicon Epitaxial Planar Switching Diode





MMBD4148 Marking Code: **5D**MMBD4148SE Marking Code: **D4**MMBD4148CC Marking Code: **D5**MMBD4148CA Marking Code: **D6**

SOT-23 Plastic Package

Absolute Maximum Ratings (T_a = 25 °C)

Parameter		Symbol	Value	Unit
Maximum Repetitive Reverse Voltage		V_{RRM}	100	V
Reverse Voltage		V_R	75	V
Average Rectified Forward Current		I _{F(AV)}	200	mA
DC Forward Current		I _{FM}	300	mA
Non-repetitive Peak Forward Surge Current	at t = 1 s at t = 1 µs	I _{FSM}	1 2	А
Total Device Dissipation		P _{tot}	350	mW
Operating Junction Temperature		T _j	150	°C
Storage Temperature Range		T_{stg}	- 55 to + 150	°C

Characteristics at T_a = 25 °C

Parameter	Symbol	Min.	Max.	Unit
Forward Voltage at I _F = 10 mA	V _F	-	1	٧
Reverse Breakdown Voltage at I_R = 100 μ A at I_R = 5 μ A	$V_{(BR)R}$	100 75	- -	V
Reverse Current at V_R = 20 V at V_R = 75 V at V_R = 20 V, T_a = 150 °C	I _R	- - -	25 5 50	nΑ μΑ μΑ
Reverse Recovery Time at I_F = 10 mA, V_R = 6 V, I_{RR} = 1 mA, R_L = 100 Ω	t _{rr}	-	4	ns
Total Capacitance at $V_R = 0 V$, $f = 1 MHz$	Ст	-	4	pF

T_A = 0°C

1.5

1.0



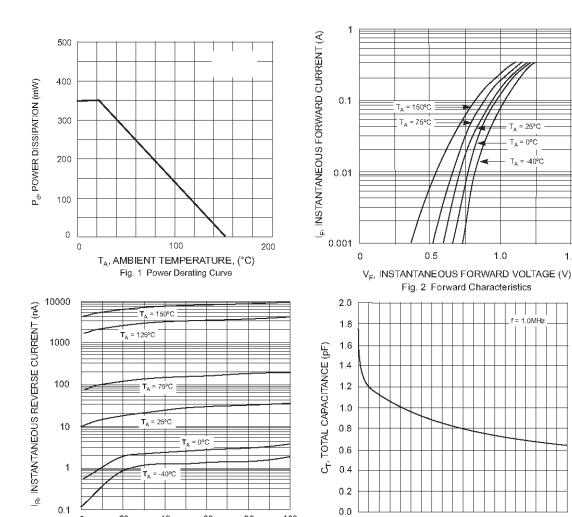
Silicon Epitaxial Planar Switching Diode

20

40

V_R, INSTANTANEOUS REVERSE VOLTAGE (V)

Fig. 3 Typical Reverse Characteristics



80

100

V_R, REVERSE VOLTAGE (V) Fig. 4 Typical Capacitance vs. Reverse Voltage

20

30

40

10

0

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